SEMICONDUCTOR

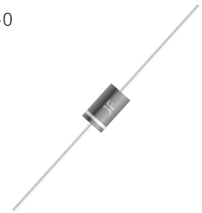
SR220 THRU SR2200

SCHOTTKY BARRIER RECTIFIER

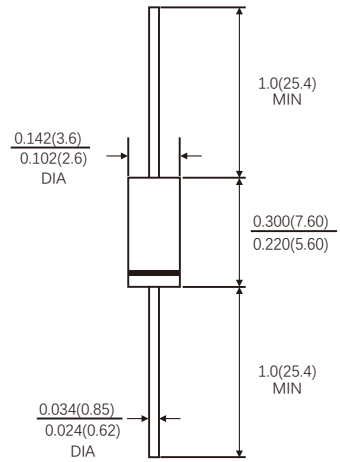
Reverse Voltage - 20 to 200 Volts
Forward Current - 2.0Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2015/863/EU



DO-15



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC DO-15 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.014ounce, 0.39 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

Parameters		Symbols	SR 220	SR 230	SR 240	SR 260	SR 2100	SR 2150	SR 2200	Units
Maximum repetitive peak reverse voltage		V_{RRM}	20	30	40	60	100	150	200	Volts
Maximum RMS voltage		V_{RMS}	14	21	28	42	71	105	140	Volts
Maximum DC blocking voltage		V_{DC}	20	30	40	60	100	150	200	Volts
Maximum average forward rectified current		$I_{(AV)}$	2.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		I_{FSM}	50.0							Amps
Maximum instantaneous forward voltage at 2.0 A(Note 1)		V_F	0.55			0.70	0.85	0.90	0.95	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	T_j=25°C	I_R	100				20			μA
	T_j=100°C		5.0				-			mA
	T_j=125°C		-				3.0			
Typical junction capacitance(Note 3)		C_J	105			80	60	40		pF
Typical thermal resistance(Note 2)	Junction-Abient Junction-Lead	RθJA RθJL	45.0 14.0							°C/W
Operating junction temperature range		T_J	-55 to+150							°C
Storage temperature range		T_{STG}	-55 to+150							°C

Notes: 1.Pulse test: 300μs pulse width,1% duty cycle
2.Thermal resistance from junction to lead, and/or to ambient P.C.B. mounted with 0.375"(9.5mm) lead length with 1.5 X1.5"(38X38mm)copper pads
3.Measured at 1.0MHz and reverse voltage of 4.0 volts

FIG.1-FORWARD CURRENT DERATING CURVE

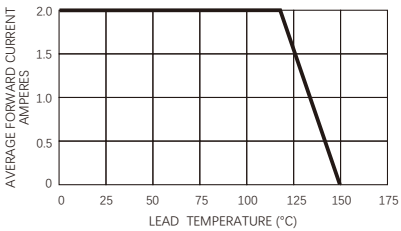


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

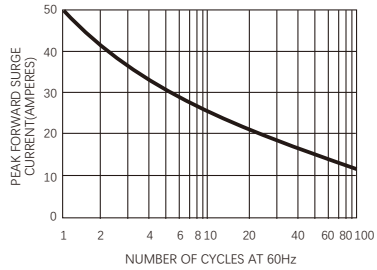


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

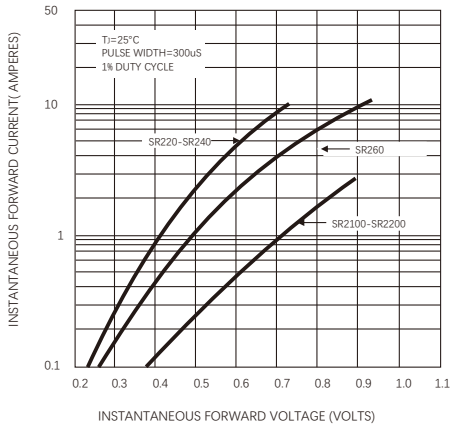


FIG.4-TYPICAL REVERSE CHARACTERISTICS

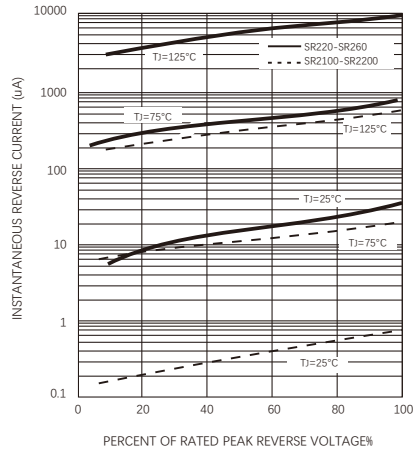
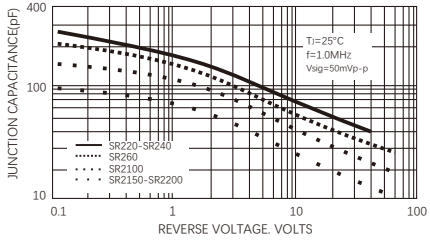


FIG.5-TYPICAL JUNCTION CAPACITANCE



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